

Rev. V2

#### **Features**

- 75 Ω Input / Output Match
- 3.8 dB Noise Figure
- 9 dB Gain
- Lead-Free SOT-89 Package
- Halogen-Free "Green" Mold Compound
- RoHS\* Compliant and 260°C Reflow Compatible

#### **Description**

M/A-COM's MAAM-007807 CATV amplifier is a GaAs MMIC which exhibits low distortion in a miniature lead-free surface mount package. The MAAM-007807 employs a monolithic single stage design featuring a convenient 75  $\Omega$  input/output impedance that minimizes the number of external components required.

The MAAM-007807 provides low noise and high linearity. It is ideally suited for set top boxes, home gateways and other broadband internet based appliances.

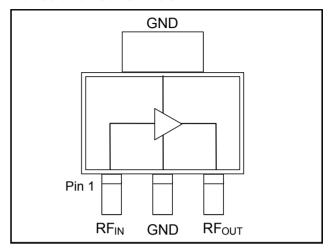
The MAAM-007807 is fabricated using M/A-COM's pHEMT process to realize low noise and low distortion. The process features full passivation for robust performance and reliability.

# Ordering Information 1,2

Part Number	Package
MAAM-007807-TR1000	1000 piece reel
MAAM-007807-TR3000	3000 piece reel
MAAM-007807-000SMB	Sample Test Board

- 1. Reference Application Note M513 for reel size information.
- 2. All sample boards include 5 loose parts.

#### **Functional Schematic**



### **Pin Configuration**

Pin No.	Pin Name	Description	
1	RF <sub>IN</sub>	RF Input	
2	GND	Ground	
3	RF <sub>out</sub>	RF Output / Drain Supply	

# **Absolute Maximum Ratings** 3,4,5

Parameter	Absolute Maximum	
RF Input Power	8 dBm	
Voltage	8.0 volts	
Operating Temperature	-40°C to +85°C	
Junction Temperature <sup>6</sup>	+150°C	
Storage Temperature	-65°C to +150°C	

- 3. Exceeding any one or combination of these limits may cause permanent damage to this device.
- M/A-COM does not recommend sustained operation near these survivability limits.
- 5. These operating conditions will ensure MTTF >  $1 \times 10^6$  hours.
- Junction Temperature (T<sub>J</sub>) = T<sub>C</sub> + Θjc \* (V \* I)
  Typical thermal resistance (Θjc) = 86° C/W.
  - a) For  $T_C = 25^{\circ}C$ ,

 $T_J = 51^{\circ}C @ 5 V, 60 mA$ 

b) For  $T_C = 85^{\circ}C$ ,

T<sub>J</sub> = 109°C @ 5 V, 55 mA

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<sup>\*</sup> Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

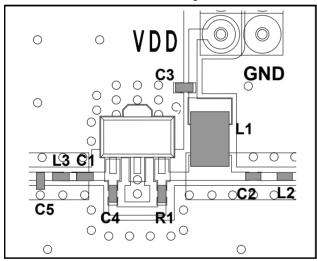


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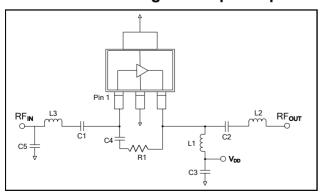
## Electrical Specifications: $T_A = 25$ °C, Freq: 50 - 1000 MHz, $V_{DD} = 5$ Volts, $Z_0 = 75$ $\Omega$

Parameter	Test Conditions	Units	Min.	Тур.	Max.
Gain	_	dB	8	9	10
Gain Flatness	_	dB	_	0.4	0.8
Noise Figure	_	dB	_	3.8	4.8
Input Return Loss	_	dB	_	18	_
Output Return Loss	_	dB	_	18	_
Output IP3	6 MHz Spacing, +4 dBm output per tone	dBm	_	35	_
Composite Triple Beat, CTB	132 channels, +15 dBmV / channel at the input.	dBc	_	-75	_
Composite Second Order, CSO	132 channels, +15 dBmV / channel at the input.	dBc	_	-65	_
P1dB	_	dBm		17	_
I <sub>DD</sub>	5 Volts	mA	50	60	70

### **Recommended Board Layout**



#### **Schematic Including Off-Chip Components**



### **Off-Chip Component Values**

Component	Value	Package		
C1 - C4	0.01 μF	0402		
C5	0.8 pF	0402		
L1 <sup>7</sup>	1 μH	1210		
L2	3.3 nH	0402		
L3	6.8 nH	0402		
R1	300 Ω	0402		

<sup>7.</sup> L1 supplied from EPCOS, part number B82422A1102K100

### **Handling Procedures**

Please observe the following precautions to avoid damage:

#### **Static Sensitivity**

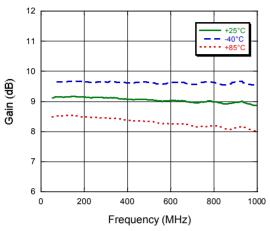
Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by electricity. Proper ESD control techniques should be used when handling these devices.



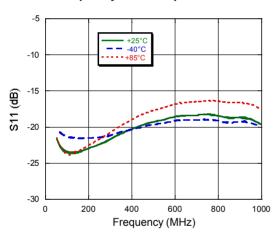
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### **Typical Performance Curves**

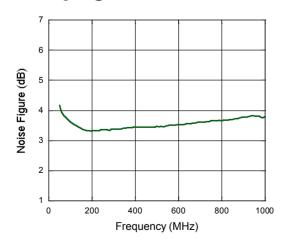
#### Gain vs. Frequency over Temperature



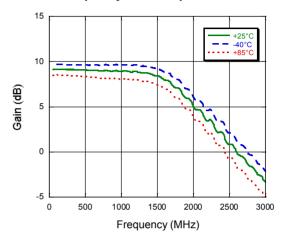
#### S11 vs. Frequency over Temperature



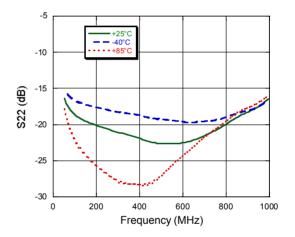
#### Noise Figure @ +25° C



#### Gain vs. Frequency over Temperature to 3 GHz



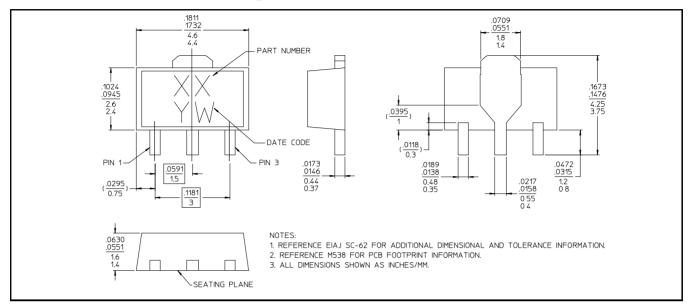
**S22** 





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## Lead-Free SOT-89 Plastic Package<sup>†</sup>



<sup>†</sup> Reference Application Note M538 for lead-free solder reflow recommendations. Meets JEDEC moisture sensitivity level 1 requirements. Plating is 100% matte tin over copper.